

CMOS Digital Integrated Circuits Silicon Monolithic

TC74VHCV240FK,TC74VHCV244FK

1. Functional Description

Octal Schmitt Bus Buffer
 TC74VHCV240FK: Inverted, 3-State Outputs
 TC74VHCV244FK: Non-Inverted, 3-State Outputs

2. General

The TC74VHCV240FK, TC74VHCV244FK are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate CMOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The TC74VHCV240FK is an inverting 3-state buffer having two active-low output enables. The TC74VHCV244FK is a non-inverting 3-state buffer, and has two active-low output enables.

Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the TC74VHCV240FK, TC74VHCV244FK are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

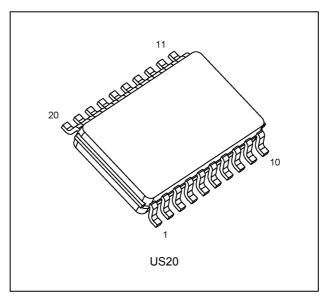
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, etc.

Note: Output in off-state

3. Features

- (1) High speed: $t_{pd} = 3.9 \text{ ns}$ (typ.) at $V_{CC} = 5.0 \text{ V}$
- (2) Low power dissipation: $I_{CC} = 2.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (3) Wide operating voltage range: $V_{CC(opr)} = 1.8 \text{ V}$ to 5.5 V
- (4) Output current: $|I_{OH}|/I_{OL} = 16$ mA (min) ($V_{CC} = 4.5$ V)
- (5) Power-down protection provided on all inputs.
- (6) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 240 or 244 type.

4. Packaging



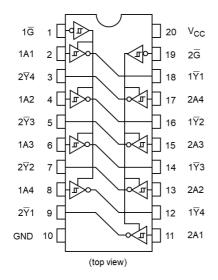
Start of commercial production

2009-12

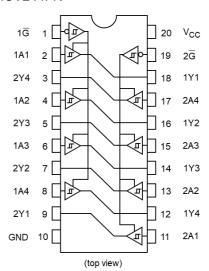


5. Pin Assignment

TC74VHCV240FK

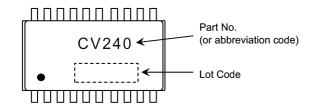


TC74VHCV244FK

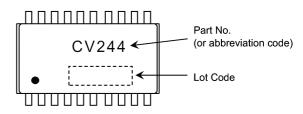


6. Marking

TC74VHCV240FK



TC74VHCV244FK



7. Truth Table

Input G	Input An	Output Yn	Output \overline{Y} n		
L	L	L	Н		
L	Н	Н	L		
Н	X	Z	Z		

X: Don't care

Z: High impedance Yn: TC74VHCV244FK

Yn: TC74VHCV240FK



8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-50	mA
Output diode current	I _{OK}	(Note 3)	±50	mA
Output current	I _{OUT}		±50	mA
Power dissipation	P _D		180	mW
V _{CC} /ground current	I _{CC}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND, V_{OUT} > V_{CC}

9. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}			1.8 to 5.5	V
Input voltage	V _{IN}			0 to 5.5	V
Output voltage	V _{OUT}	(Note 1)		0 to 5.5	٧
		(Note 2)	_	0 to V _{CC}	
Operating temperature	T _{opr}		_	-40 to 85	°C
Input rise and fall times	dt/dv		V_{CC} = 3.3 \pm 0.3 V	0 to 20	ms/V
			V_{CC} = 5.0 \pm 0.5 V	0 to 1	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state. Note 2: High (H) or Low (L) state.



10. Electrical Characteristics

10.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V_P	_		1.8	_	_	1.65	V
				2.3	_	_	1.85	
				3.0	_	_	2.20	
				4.5	_	_	3.15	
				5.5	_	_	3.85	
Negative threshold voltage	V _N	_		1.8	0.15	_	_	V
				2.3	0.45	_	_	
				3.0	0.90	_	_	
				4.5	1.35	_	_	
				5.5	1.65	_	_	
Hysteresis voltage	V _H	_		1.8	0.15	_	1.05	V
				2.3	0.20	_	1.10	
				3.0	0.30	_	1.20	
				4.5	0.40	_	1.40	
				5.5	0.50	_	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	1.8	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I _{OH} = -8 mA	3.0	2.58	_	_	
			I _{OH} = -16 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 8 mA	3.0	_	_	0.36	
			I _{OL} = 16 mA	4.5	_	_	0.44	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.8 to 5.5	_	_	±0.5	μА
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	_	0.5	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	μА
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND		5.5	_	_	2.0	μА



10.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_		1.8	_	1.65	V
				2.3	_	1.85	
				3.0	_	2.20	
				4.5		3.15	
				5.5		3.85	
Negative threshold voltage	V _N	_		1.8	0.15	_	V
				2.3	0.45	_	
				3.0	0.90	_	
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V _H	_		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -50 μA	1.8	1.7	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I_{OH} = -8 mA	3.0	2.48	_	
			I _{OH} = -16 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 50 μA	1.8		0.1	V
				3.0	_	0.1	
				4.5		0.1	
			I_{OL} = 8 mA	3.0		0.44	
			I _{OL} = 16 mA	4.5		0.55	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.8 to 5.5		±5.0	μА
Power-OFF leakage current	I _{OFF}	$V_{IN}/V_{OUT} = 5.5 V$		0	_	5.0	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±1.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5		20.0	μА



10.3. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	TC74VHCV240FK	t_{PLH},t_{PHL}		_	2.5 ± 0.2	15	_	6.4	11.6	ns
						50	_	9.2	14.4	
					3.3 ± 0.3	15	_	5.0	7.5	
						50	_	7.0	11.0	
					5.0 ± 0.5	15	_	3.9	5.5	
						50	_	5.4	7.5	
Propagation delay time	TC74VHCV244FK	t _{PLH} ,t _{PHL}		_	2.5 ± 0.2	15	_	6.7	12.5	ns
						50	_	9.5	15.3	
					3.3 ± 0.3	15	_	5.0	8.4	
						50	_	7.2	11.9	
					5.0 ± 0.5	15	_	3.8	5.5	
						50	_	5.4	7.5	
3-state output enable		t_{PZL}, t_{PZH}		$R_L = 1 k\Omega$	2.5 ± 0.2	15	_	7.8	14.6	ns
time						50	_	11.1	17.8	
					3.3 ± 0.3	15	_	5.7	10.6	
						50	_	8.4	14.1	
					5.0 ± 0.5	15	_	4.1	7.3	
						50	_	6.2	9.3	
3-state output disable		t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	_	14.3	19.2	ns
time					3.3 ± 0.3	50	_	10.9	14.0	
					5.0 ± 0.5	50	_	8.7	9.2	
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	2.5 ± 0.2	50	_	_	2.0	ns
					3.3 ± 0.3	50	_	_	1.5	
					5.0 ± 0.5	50	_	_	1.0	
Input capacitance		C _{IN}		_		-	_	4	10	pF
Output capacitance		C _{OUT}		_	,		_	6	_	рF
Power dissipation	TC74VHCV240FK	C _{PD}	(Note 2)	_			_	20	_	pF
capacitance	TC74VHCV244FK	C _{PD}	(Note 2)	_				21	_	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.



10.4. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	TC74VHCV240FK	t_{PLH}, t_{PHL}		_	2.5 ± 0.2	15	1.0	14.0	ns
						50	1.0	17.0	
					3.3 ± 0.3	15	1.0	9.0	
						50	1.0	12.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
Propagation delay time	TC74VHCV244FK	t_{PLH}, t_{PHL}		_	2.5 ± 0.2	15	1.0	15.0	ns
						50	1.0	18.0	
					3.3 ± 0.3	15	1.0	10.0	
						50	1.0	13.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
3-state output enable time		t_{PZL}, t_{PZH}		$R_L = 1 k\Omega$	2.5 ± 0.2	15	1.0	17.0	ns
						50	1.0	21.0	
					3.3 ± 0.3	15	1.0	12.5	
						50	1.0	16.0	
					5.0 ± 0.5	15	1.0	8.5	
						50	1.0	10.5	
3-state output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	1.0	21.0	ns
					3.3 ± 0.3	50	1.0	16.0	
					5.0 ± 0.5	50	1.0	10.5	
Output skew		t_{osLH}, t_{osHL}	(Note 1)	_	2.5 ± 0.2	50	_	2.0	ns
					3.3 ± 0.3	50	_	1.5	
					5.0 ± 0.5	50	_	1.0	
Input capacitance		C _{IN}		_			_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

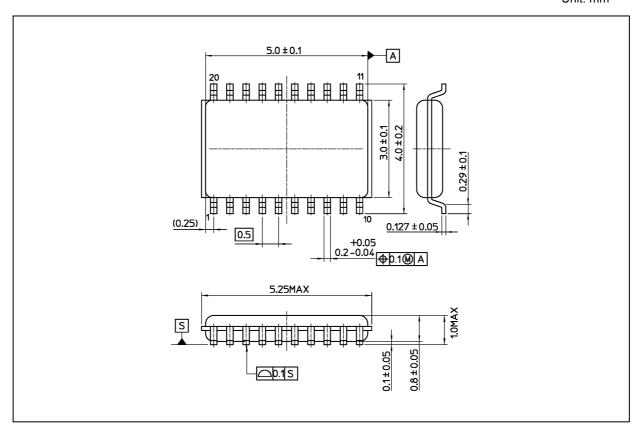
10.5. Noise Characteristics (Unless otherwise specified, T_a = 25 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	3.3	0.45		V
			5.0	0.9		
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	3.3	-0.1		V
			5.0	-0.3	_	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0		3.5	V
Maximum low-level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0		1.5	V



Package Dimensions

Unit: mm



Weight: 0.03 g (typ.)

	Package Name(s)
Nickname: US20	



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